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MM74C914 Hex Schmitt Trigger with Extended Input Voltage

General Description

The MM74C914 is a monolithic CMOS Hex Schmitt trigger with special input protection scheme. This scheme allows the input voltage levels to exceed V_{CC} or ground by at least 10V (V_{CC} –25V to GND + 25V), and is valuable for applications involving voltage level shifting or mismatched power supplies.

The positive and negative-going threshold voltages, V_{T+} and $V_{T-},$ show low variation with respect to temperature

(typ 0.0005V/°C at V_{CC} = 10V). And the hysteresis, $V_{T+}-V_{T-} \ge 0.2 \; V_{CC}$ is guaranteed.

October 1987

Revised January 1999

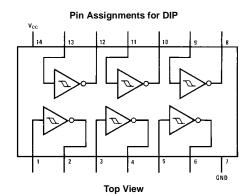
Features

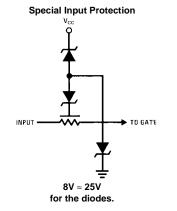
- Hysteresis: 0.45 V_{CC} (typ.) 0.2 V_{CC}guaranteed
 Special input protection: Extended Input Voltage
- Range Wide supply voltage range: 3V to 15V
- High noise immunity: 0.7 V_{CC} (typ.)
- Low power TTL compatibility: Fan out of 2 driving 74L

Ordering Code:

Order Number	Package Number	Package Description			
MM74C914M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow			
MM74C914N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.					

Connection Diagrams





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Absolute Maximum R	Ratings(Note 1)	(
Voltage at any Input Pin	V_{CC} – 25V to GND + 25V	1
Voltage at any other Pin	-0.3Vto V _{CC} + 0.3V	L
Operating Temperature Range (T _A)	-40°C to +85°C	
Storage Temperature Range (T _S)	$-65^{\circ}C$ to $+150^{\circ}C$	
Power Dissipation		
Dual-In-Line	700 mW	
Small Outline	500mW	

Operating V _{CC} Range	3V to 15V
Absolute Maximum (V _{CC})	18V
Lead Temperature (T _L)	
(Soldering, 10 seconds)	300°C

+150°C
 Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range", they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

DC Electrical Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Units
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V _{T+}	Positive Going Threshold Voltage	$V_{CC} = 5V$	3.0	3.6	4.3	V
		$V_{CC} = 10V$	6.0	6.8	8.6	V
		$V_{CC} = 15V$	9.0	10	12.9	
/ _{T-}	Negative Going Threshold Voltage	$V_{CC} = 5V$	0.7	1.4	2.0	V
		$V_{CC} = 10V$	1.4	3.2	4.0	V
		$V_{CC} = 15V$	2.1	5	6.0	
/ _{T+} – V _{T-}	Hysteresis	$V_{CC} = 5V$	1.0	2.2	3.6	V
		$V_{CC} = 10V$	2.0	3.6	7.2	V
		$V_{CC} = 15V$	3.0	5	10.8	V
OUT(1)	Logical"1" Output Voltage	$V_{CC} = 5V, I_{O} = -10 \ \mu A$	4.5			V
		$V_{CC} = 10V, I_{O} = -10 \ \mu A$	9.0			V
OUT(0)	Logical "0" Output Voltage	$V_{CC} = 5V, I_{O} = +10 \ \mu A$			0.5	V
		$V_{CC} = 10V, I_{O} = +10 \ \mu A$			1.0	V
IN(1)	Logical "1" Input Current	$V_{CC} = 15V, V_{IN} = 25V$		0.005	5.0	μA
N(0)	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = -10V$	-100	-0.005		μA
I _{CC}	Supply Current	$V_{CC} = 15V, V_{IN} = -10V/25V$		0.05	300	μA
		$V_{CC} = 5V$, $V_{IN} = -2.5V$ (Note 2)		20		μA
		$V_{CC} = 10V, V_{IN} = 5V$ (Note 2)		200		μA
		$V_{CC} = 15V$, $V_{IN} = 7.5V$ (Note 2)		600		μA
CMOS/LPTT	LINTERFACE					
/ _{IN(1)}	Logical "1" Input Voltage	$V_{CC} = 5V$	4.3			V
/ _{IN(0)}	Logical "0" Input Voltage	$V_{CC} = 5V$			0.7	V
OUT(1)	Logical "1" Output Voltage	$V_{CC} = 4.75 V$, $I_O = -360 \ \mu A$	2.4			V
OUT(0)	Logical "0" Output Voltage	$V_{CC} = 4.75 V$, $I_{O} = 360 \ \mu A$			0.4	V
OUTPUT DR	IVE (See Family Characteristics Data Sh	neet) (Short Circuit Current)				
SOURCE	Output Source Current	$V_{CC} = 5V$, $V_{OUT} = 0V$, $T_A = 25^{\circ}C$	-1.75	-3.3		mA
	(P-Channel)					
SOURCE	Output Source Current	$V_{CC} = 10V, V_{OUT} = 0V, T_A = 25^{\circ}C$	-8.0	-15		mA
	(P-Channel)					
SINK	Output Sink Current	$V_{CC} = 5V$, $V_{OUT} = V_{CC}$, $T_A = 25^{\circ}C$	1.75	3.6		mA
	(N-Channel)					
SINK	Output Sink Current	$V_{CC} = 10V$, $V_{OUT} = V_{CC}$, $T_A = 25^{\circ}C$	8.0	16		mA
	(N-Channel)					

AC	Electi	rical	Cha	ract	teris	stics	(Note 3)
-							

Symbol	Parameter	Conditions	Min	Тур	Мах	Units
t _{PHL}	Propagation Delay from Input to Output	$V_{CC} = 5V$		220	400	ns
t _{PLH}		$V_{CC} = 10V$		80	200	ns
C _{IN}	Input Capacitance	Any Input (Note 4)		5		pF
C _{PD}	Power Dissipation Capacitance	Per Gate (Note 5)		20		pF

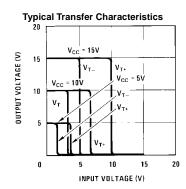
MM74C914

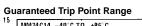
Note 3: AC Parameters are guaranteed by DC correlated testing.

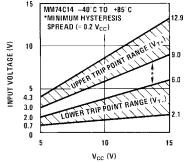
Note 4: Capacitance is guaranteed by periodic testing.

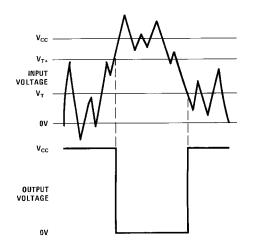
Note 5: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics Application Note, AN-90.

Typical Performance Characteristics

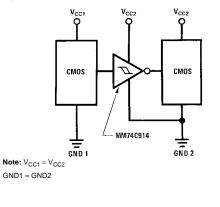








Typical Application



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